

30V P-Channel MOSFET

Product Summary

| $V_{(BR)DSS}$ | $R_{DS(on)MAX}$ | I_D |
|---------------|-----------------|-------|
| -30V | 65mΩ@-10V | -4.2A |
| | 75mΩ@-4.5V | |
| | 90mΩ@-2.5V | |

Feature

TrenchFET Power MOSFET

Exceptional on-resistance and maximum DC current capability

AEC-Q101 qualified (Automotive grade with suffix "Q".)

Exsemi technology

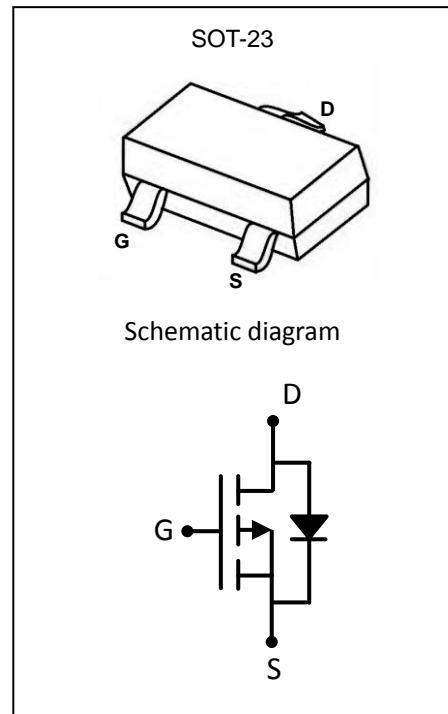
Application

DC/DC Converter

Load Switch for Portable Devices

Battery Switch

MARKING:

ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Value | Unit |
|---------------------------------------------|-----------------|----------|------|
| Drain-Source Voltage | V_{DS} | -30 | V |
| Gate-Source Voltage | V_{GS} | ± 12 | V |
| Continuous Drain Current | I_D | -4.2 | A |
| Power Dissipation | P_D | 1.2 | W |
| Thermal Resistance from Junction to Ambient | $R_{\theta JA}$ | 105 | °C/W |
| Junction Temperature | T_J | 150 | °C |
| Storage Temperature | T_{STG} | -55~+150 | °C |

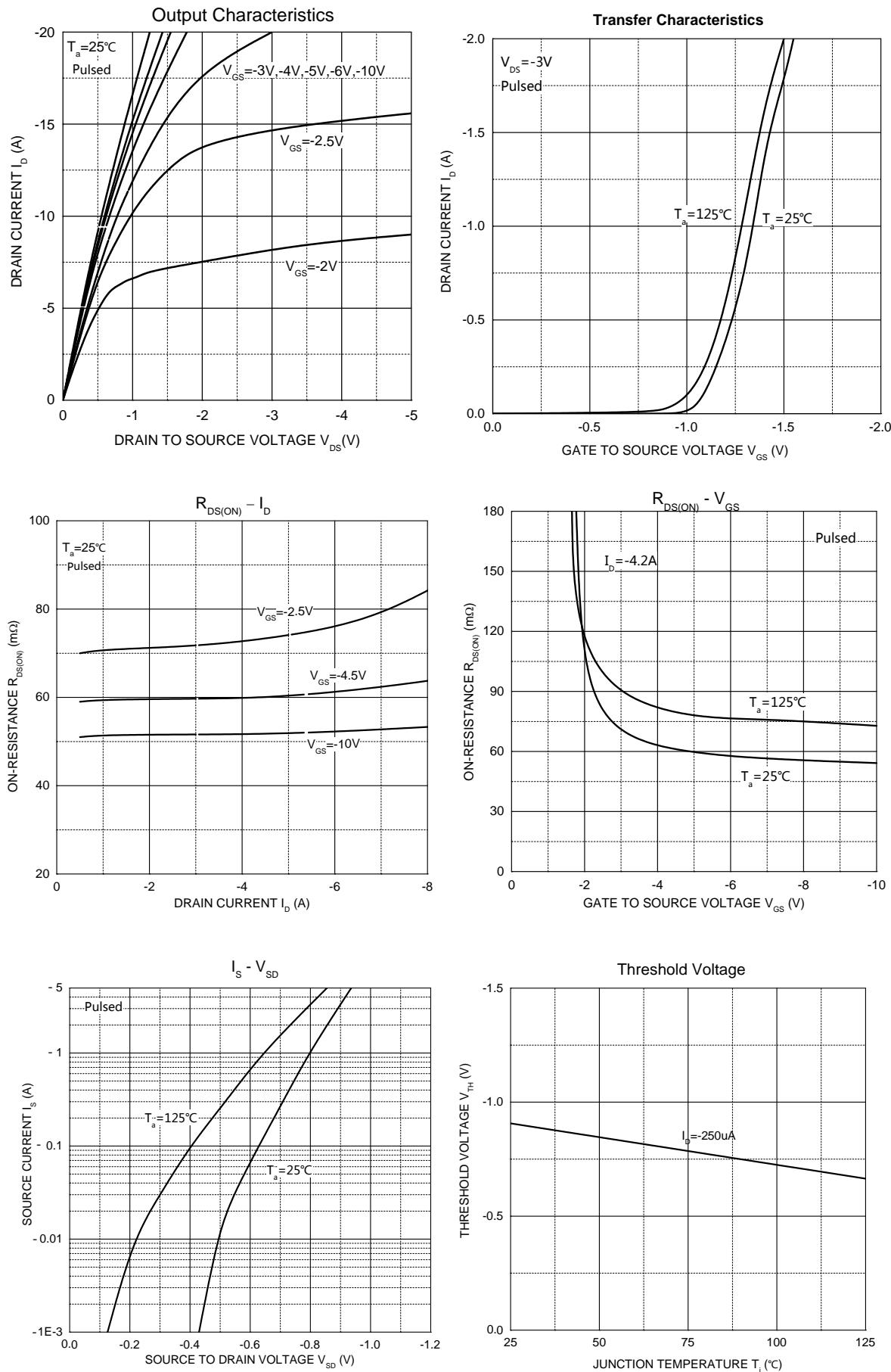
MOSFET ELECTRICAL CHARACTERISTICS($T_a=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Test Condition | Min | Type | Max | Unit |
|------------------------------------------------|-----------------------------|-------------------------------------------------------------------------------------------------------|------|------|-----------|------------------|
| Static Characteristics | | | | | | |
| Drain-source breakdown voltage | $V_{(\text{BR})\text{DSS}}$ | $V_{\text{GS}} = 0\text{V}, I_D = -250\mu\text{A}$ | -30 | | | V |
| Zero gate voltage drain current | I_{DSS} | $V_{\text{DS}} = -24\text{V}, V_{\text{GS}} = 0\text{V}$ | | | -1 | μA |
| Gate-body leakage current | I_{GSS} | $V_{\text{GS}} = \pm 12\text{V}, V_{\text{DS}} = 0\text{V}$ | | | ± 100 | nA |
| Gate threshold voltage | $V_{\text{GS}(\text{th})}$ | $V_{\text{DS}} = V_{\text{GS}}, I_D = -250\mu\text{A}$ | -0.7 | -0.9 | -1.3 | V |
| Drain-source on-resistance ⁽¹⁾ | $R_{\text{DS}(\text{on})}$ | $V_{\text{GS}} = -10\text{V}, I_D = -4.2\text{A}$ | | 50 | 65 | $\text{m}\Omega$ |
| | | $V_{\text{GS}} = -4.5\text{V}, I_D = -4\text{A}$ | | 60 | 75 | |
| | | $V_{\text{GS}} = -2.5\text{V}, I_D = -1\text{A}$ | | 70 | 90 | |
| Forward transconductance ⁽¹⁾ | g_{FS} | $V_{\text{DS}} = -5\text{V}, I_D = -4.2\text{A}$ | | 10 | | S |
| Dynamic characteristics⁽²⁾ | | | | | | |
| Input Capacitance | C_{iss} | $V_{\text{DS}} = -15\text{V}, V_{\text{GS}} = 0\text{V}, f = 1\text{MHz}$ | | 954 | | pF |
| Output Capacitance | C_{oss} | | | 115 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 77 | | |
| Switching characteristics⁽²⁾ | | | | | | |
| Turn-on delay time | $t_{\text{d}(\text{on})}$ | $V_{\text{GS}} = -10\text{V}, V_{\text{DS}} = -15\text{V}, R_L = 3.6\Omega, R_{\text{GEN}} = 6\Omega$ | | | 6.3 | ns |
| Turn-on rise time | t_r | | | | 3.2 | |
| Turn-off delay time | $t_{\text{d}(\text{off})}$ | | | | 38.2 | |
| Turn-off fall time | t_f | | | | 12 | |
| Source-Drain Diode characteristics | | | | | | |
| Diode forward current | I_S | | | | -2 | A |
| Diode pulsed forward current | I_{SM} | | | | -25 | A |
| Diode Forward voltage ⁽¹⁾ | V_{DS} | $V_{\text{GS}} = 0\text{V}, I_S = -4.2\text{A}$ | | | -1.2 | V |

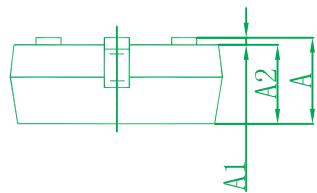
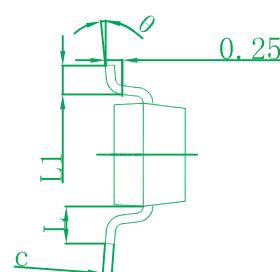
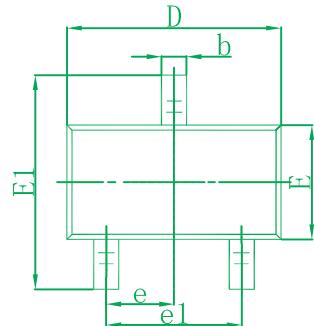
Notes:

1. Pulse test; pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.
2. Guaranteed by design, not subject to production testing.

Typical Electrical and Thermal Characteristics

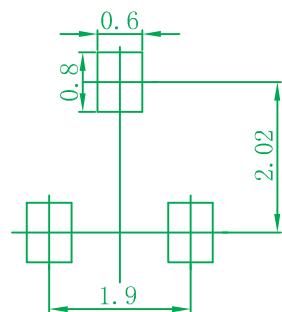


SOT-23 Package Information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|----------|---------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 0.900 | 1.150 | 0.035 | 0.045 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 0.900 | 1.150 | 0.035 | 0.045 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.080 | 0.150 | 0.003 | 0.006 |
| D | 2.800 | 3.050 | 0.110 | 0.120 |
| E | 1.200 | 1.400 | 0.047 | 0.055 |
| E1 | 2.250 | 2.550 | 0.089 | 0.100 |
| e | 0.950 TYP | | 0.037 TYP | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.550 REF | | 0.022 REF | |
| L1 | 0.360 REF | | 0.014 REF | |
| θ | 0° | 8° | 0° | 8° |

SOT-23 Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

Ordering information

| Device | Package | Shipping |
|--------|---------|-------------------------|
| EP3401 | SOT-23 | 3000/Tape&Reel(7inches) |